

RBE023N04R0SZN6

N-Channel Power [MOSFET](#)

40V - 100A - 2.3mΩ

Description

Renesas SO8-FL technology in 5x6mm² flat-lead package designed for supporting high current with copper clip-applied, compact & efficient designs and including optimal thermal performance.

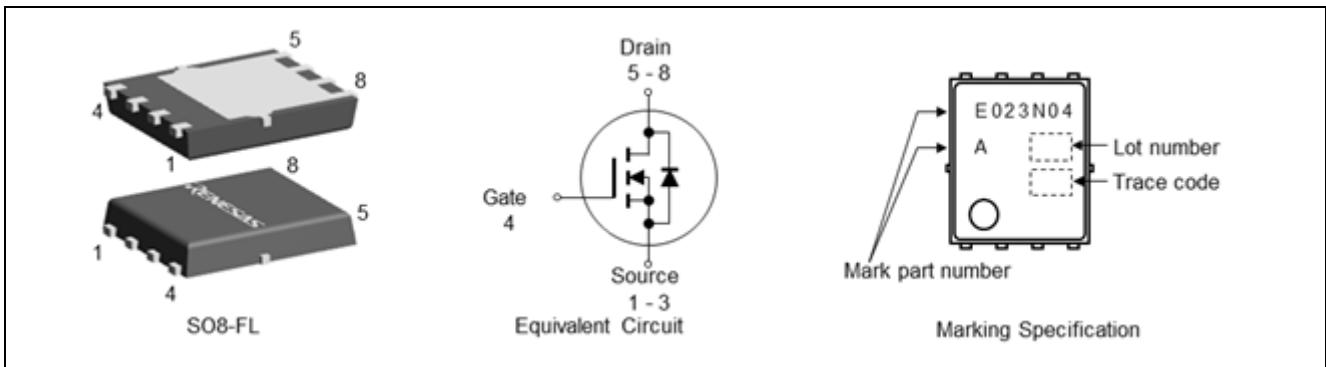
Features

- Standard level gate drive voltage: $V_{GS(th)} = 2.0\sim 4.0V$
- Low on-state resistance to minimize conduction losses: $R_{DS(on)} = 2.3m\Omega$ Max.
- Low input capacitance to minimize driver losses
- Small footprint (5x6mm²) with compact design
- Pb-free lead plating: RoHS compliant
- MSL1 classified according to IPC/JEDEC J-STD-020

Application

- Industrial: Motor Control, Power Tool, Stepper Motor, BMS, Battery Powered Application, etc.

Outline



Absolute Maximum Ratings

($T_j=25^\circ C$ unless otherwise notice.)

Item	Symbol	Ratings	Unit
Drain to Source Voltage	V_{DSS}	40	V
Gate to Source Voltage	V_{GSS}	± 20	V
Drain Current (DC)	$I_{D(DC)}$ ^{Notes1,2,5}	± 100	A
Drain Current (pulse)	$I_{D(pulse)}$ ^{Notes1,3,5}	± 300	A
Power Dissipation	P_D ^{Notes1,5}	88	W
Junction Temperature	T_j	175	$^\circ C$
Storage Temperature	T_{stg}	-55 to 175	$^\circ C$
Single Avalanche Current	I_{AS} ^{Notes4}	38	A
Single Avalanche Energy	E_{AS} ^{Notes4}	144	mJ

Thermal Resistance

Item	Symbol	Max.	Unit
Junction to Case Thermal Resistance	$R_{th(j-c)}$ ^{Notes5}	1.7	$^\circ C/W$

Electrical Characteristics

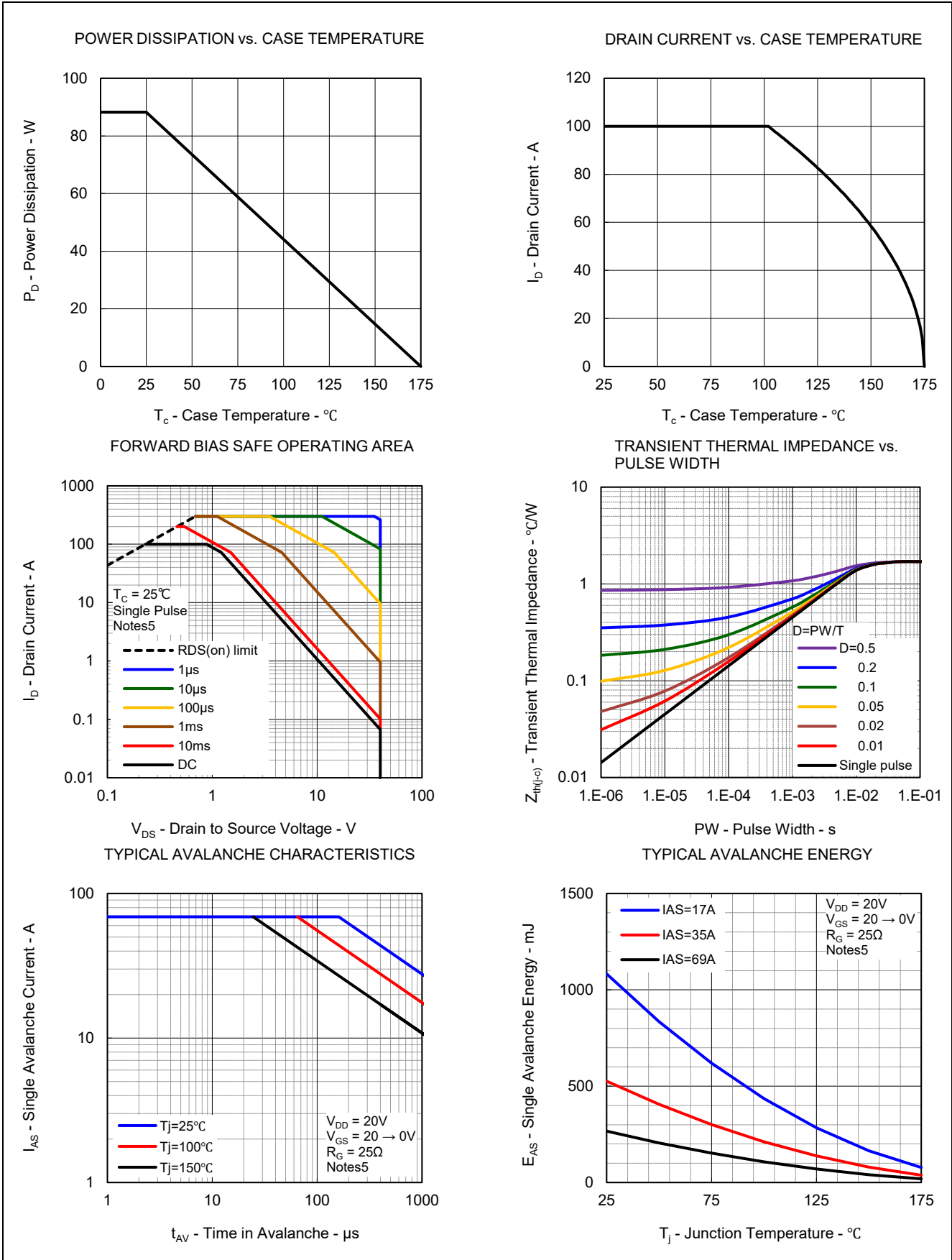
(T_j=25°C unless otherwise notice.)

Item	Symbol	Min	Typ	Max	Unit	Test Conditions
Zero Gate Voltage Drain Current	I _{DSS}	—	—	1	μA	V _{DS} = 40 V, V _{GS} = 0 V
Gate Leakage Current	I _{GSS}	—	—	±100	nA	V _{GS} = ± 20 V, V _{DS} = 0 V
Gate to Source Threshold Voltage	V _{GS(th)}	2.0	—	4.0	V	V _{DS} = V _{GS} , I _D = 250 μA
Drain to Source On-state Resistance	R _{DS(on)}	—	1.86	2.3	mΩ	V _{GS} = 10 V, I _D = 50 A
Input Capacitance	C _{iSS}	—	3200	—	pF	V _{DS} = 25 V V _{GS} = 0 V f = 1 MHz
Output Capacitance	C _{oss}	—	370	—	pF	
Reverse Transfer Capacitance	C _{rSS}	—	240	—	pF	
Gate resistance	R _g	—	1.7	—	Ω	
Turn-on Delay Time	t _{d(on)}	—	32	—	ns	
Rise Time	t _r	—	60	—	ns	V _{DD} = 20 V, I _D = 50 A V _{GS} = 10 V R _G = 5 Ω
Turn-off Delay Time	t _{d(off)}	—	70	—	ns	
Fall Time	t _f	—	17	—	ns	
Total Gate Charge	Q _g	—	60	—	nC	V _{DD} = 20 V V _{GS} = 10 V I _D = 50 A
Gate to Source Charge	Q _{gs}	—	16	—	nC	
Gate to Drain Charge	Q _{gd}	—	16	—	nC	
Body Diode Forward Voltage	V _{F(S-D)}	—	0.83	1.5	V	I _F = 50 A, V _{GS} = 0 V
Reverse Recovery Time	t _{rr}	—	46	—	ns	I _F = 50 A, V _{GS} = 0 V di/dt = 100 A/μs
Reverse Recovery Charge	Q _{rr}	—	48	—	nC	

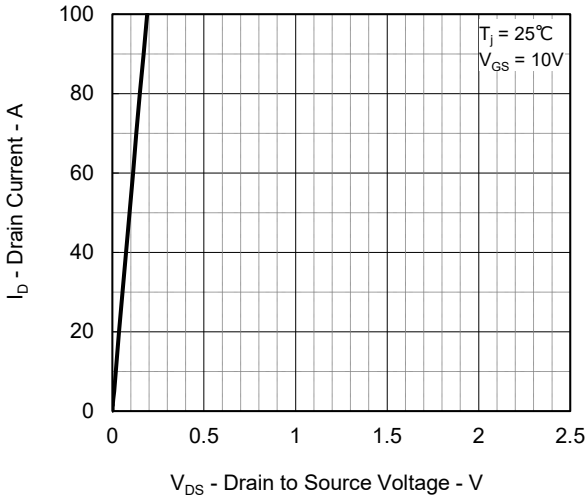
Notes 1. T_c = 25°C

2. Value is limited by overall system design including PCB.
3. PW ≤ 10 μs, Duty Cycle ≤ 1%
4. L = 100μH, V_{DD} = 20V, V_{GS} = 20 → 0V, R_G = 25 Ω
5. Defined by design. Not subject to production test.

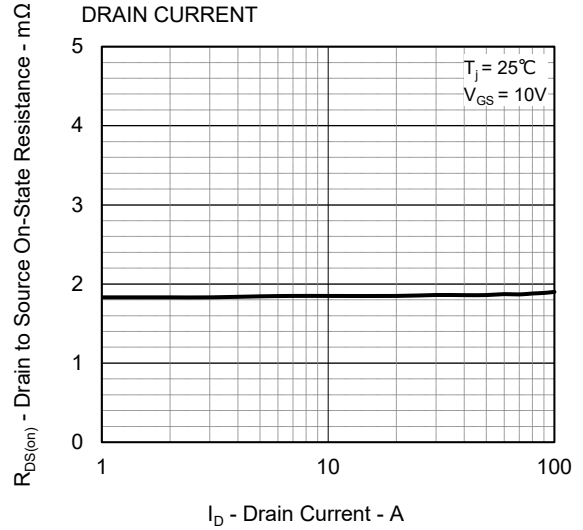
Typical Characteristics



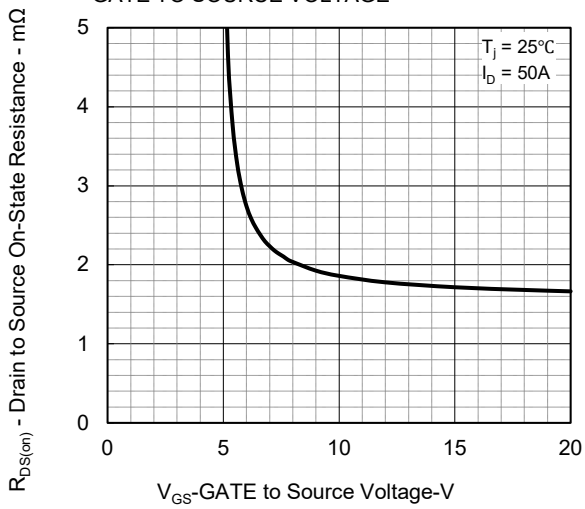
DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE



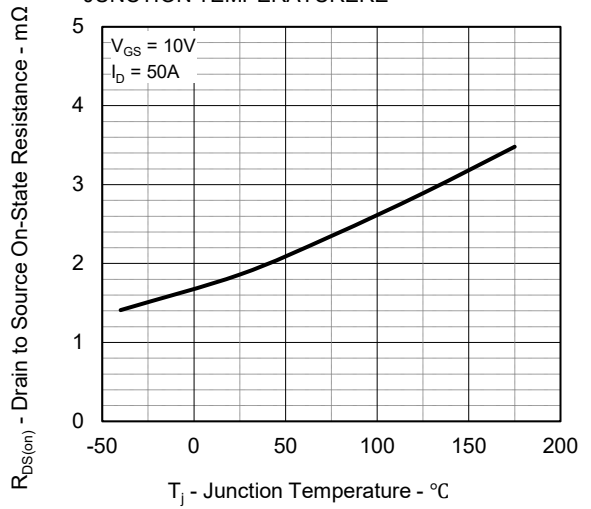
DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



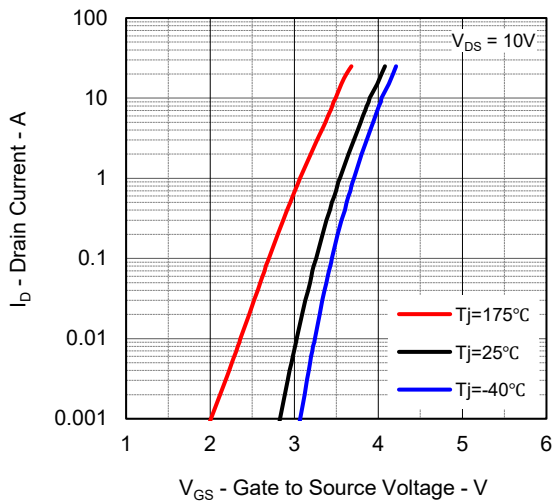
DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



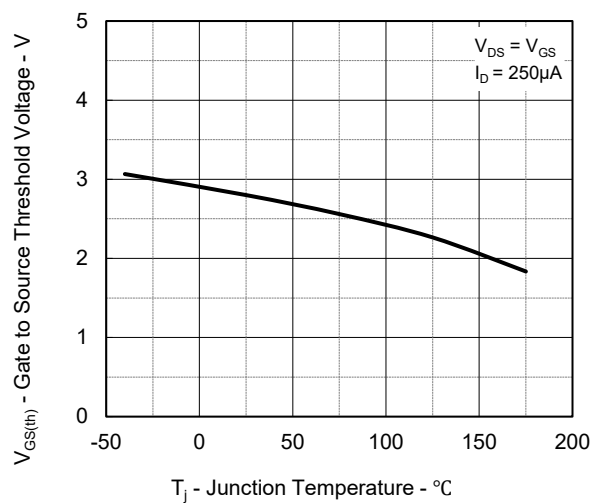
DRAIN TO SOURCE ON-STATE RESISTANCE vs. JUNCTION TEMPERATURE



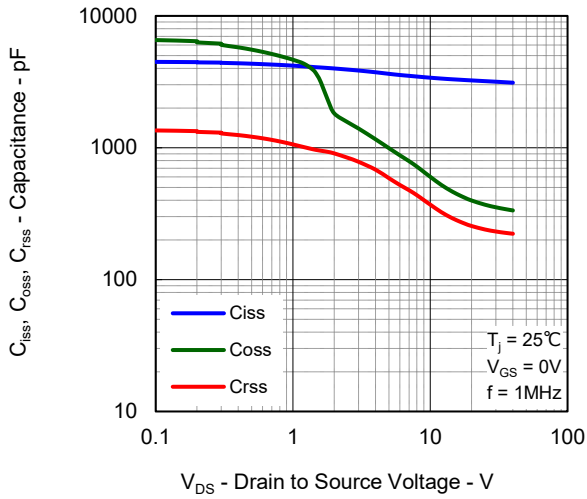
FORWARD TRANSFER CHARACTERISTICS



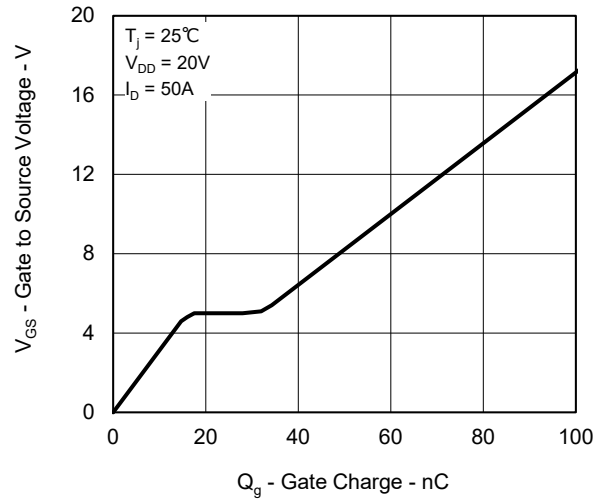
GATE TO SOURCE THRESHOLD VOLTAGE vs. JUNCTION TEMPERATURE



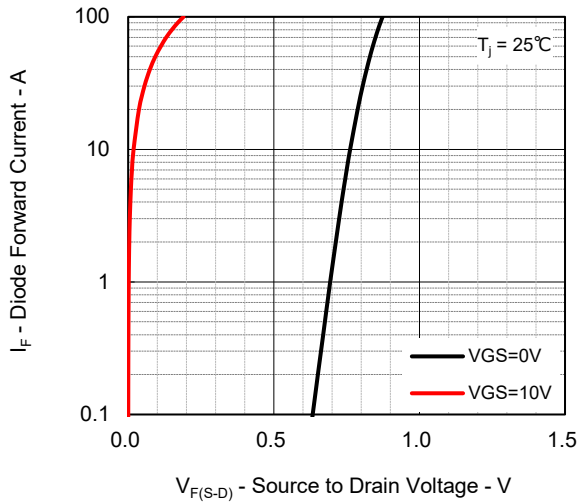
CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



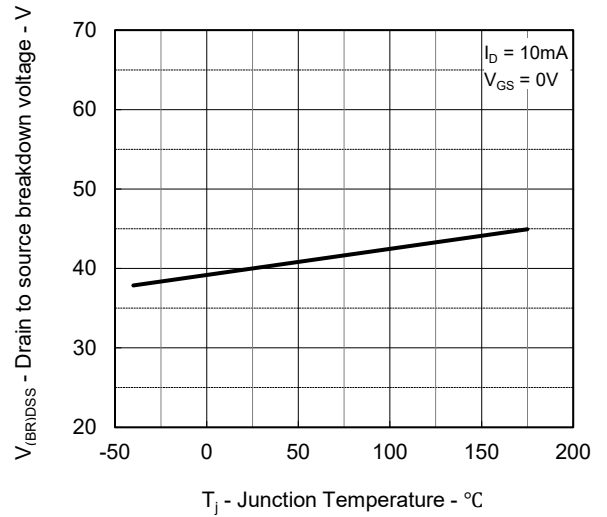
DYNAMIC INPUT/OUTPUT CHARACTERISTICS



SOURCE TO DRAIN DIODE FORWARD VOLTAGE



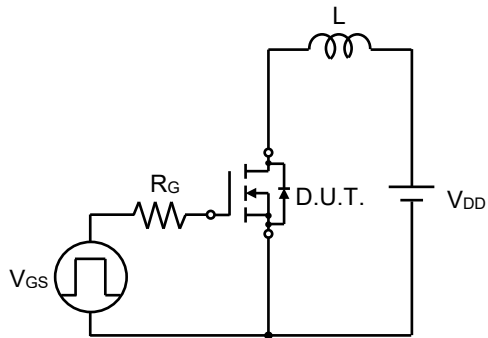
DRAIN TO SOURCE BREAKDOWN VOLTAGE vs. JUNCTION TEMPERATURE



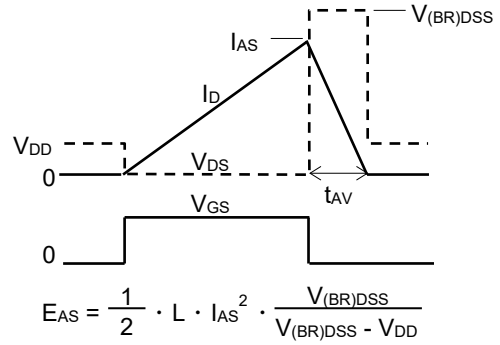
Test Circuit

Avalanche

Test Circuit

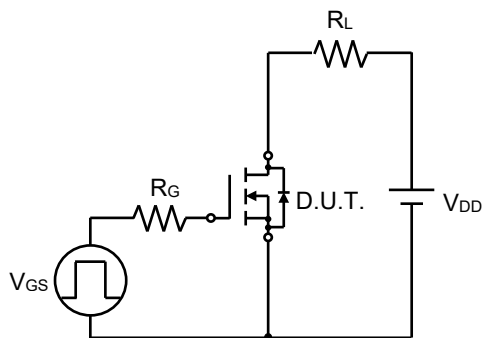


Waveform

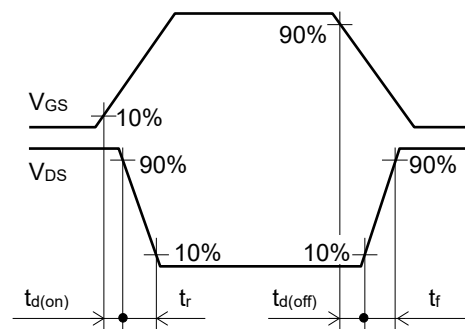


Switching Time

Test Circuit

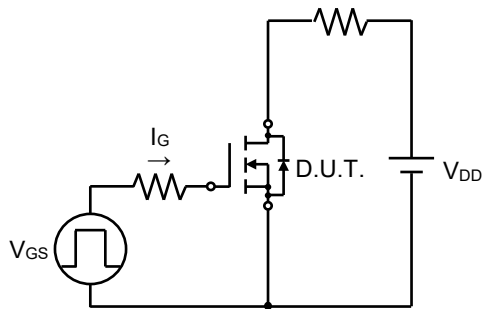


Waveform

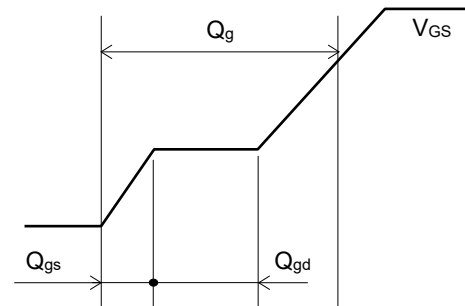


Gate Charge

Test Circuit

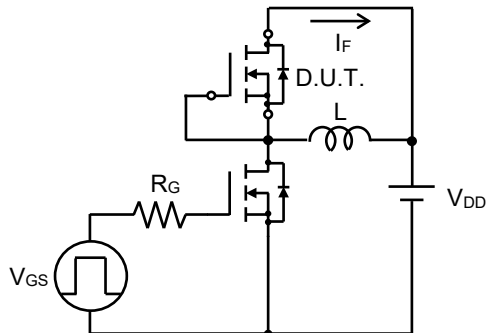


Waveform

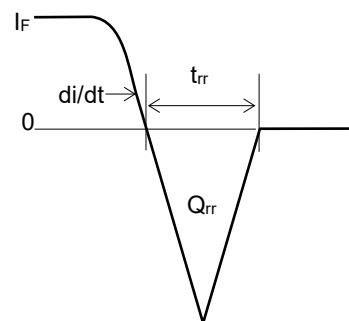


Reverse Recovery

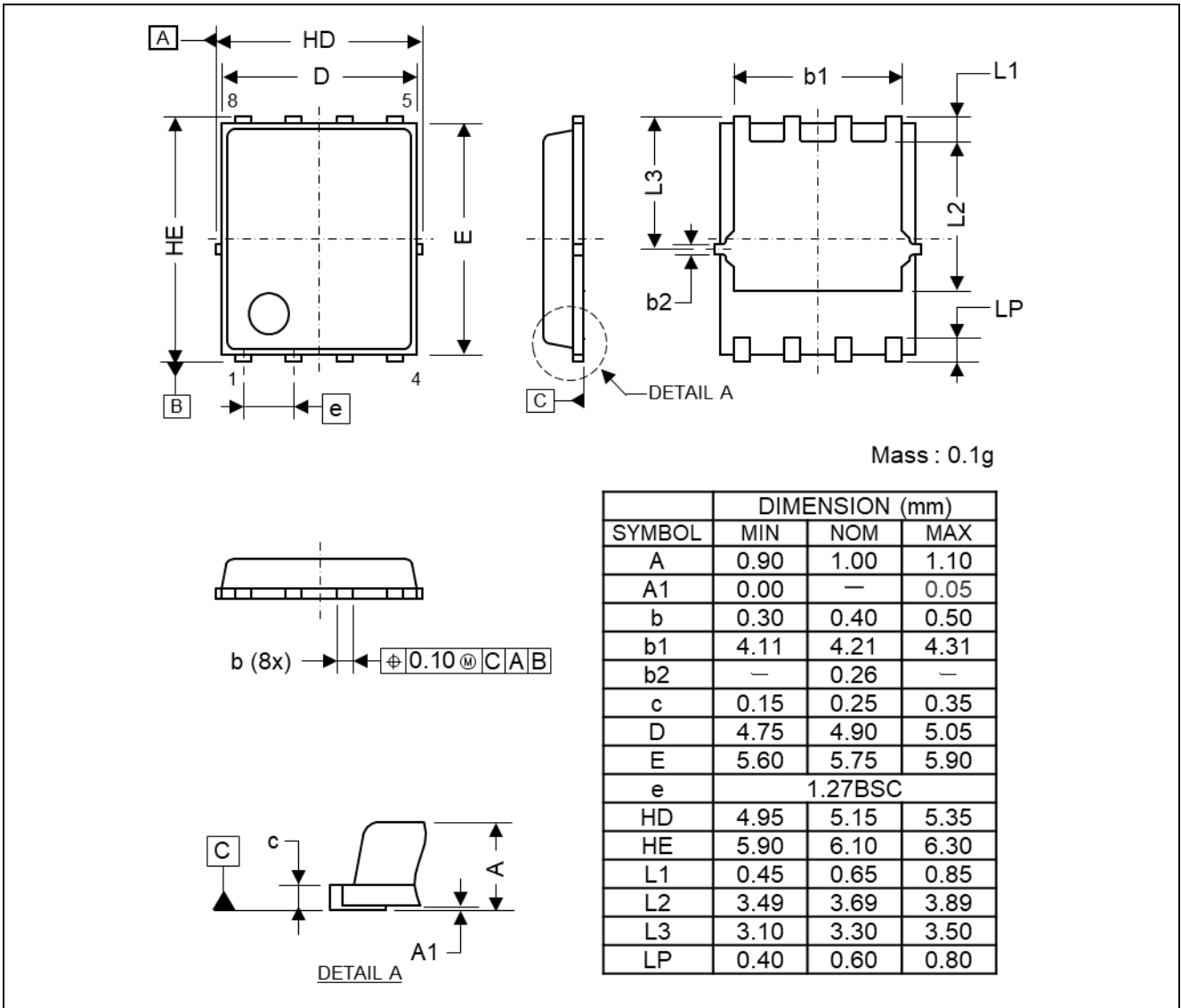
Test Circuit



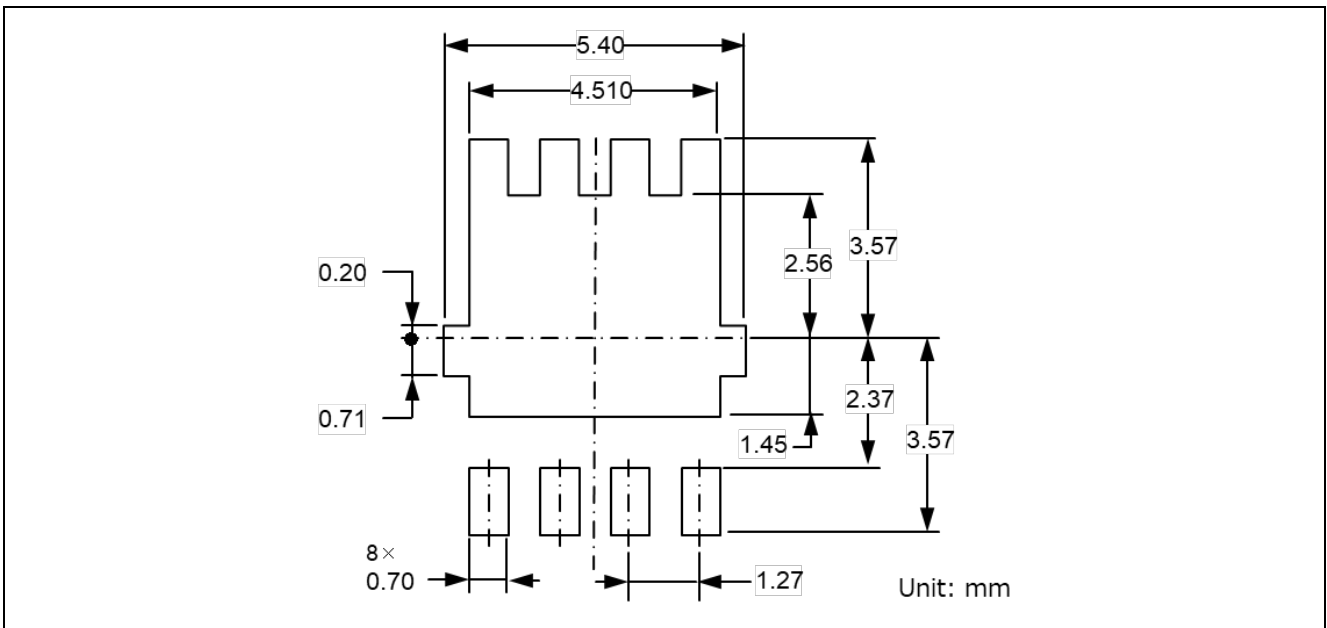
Waveform



Package Dimensions



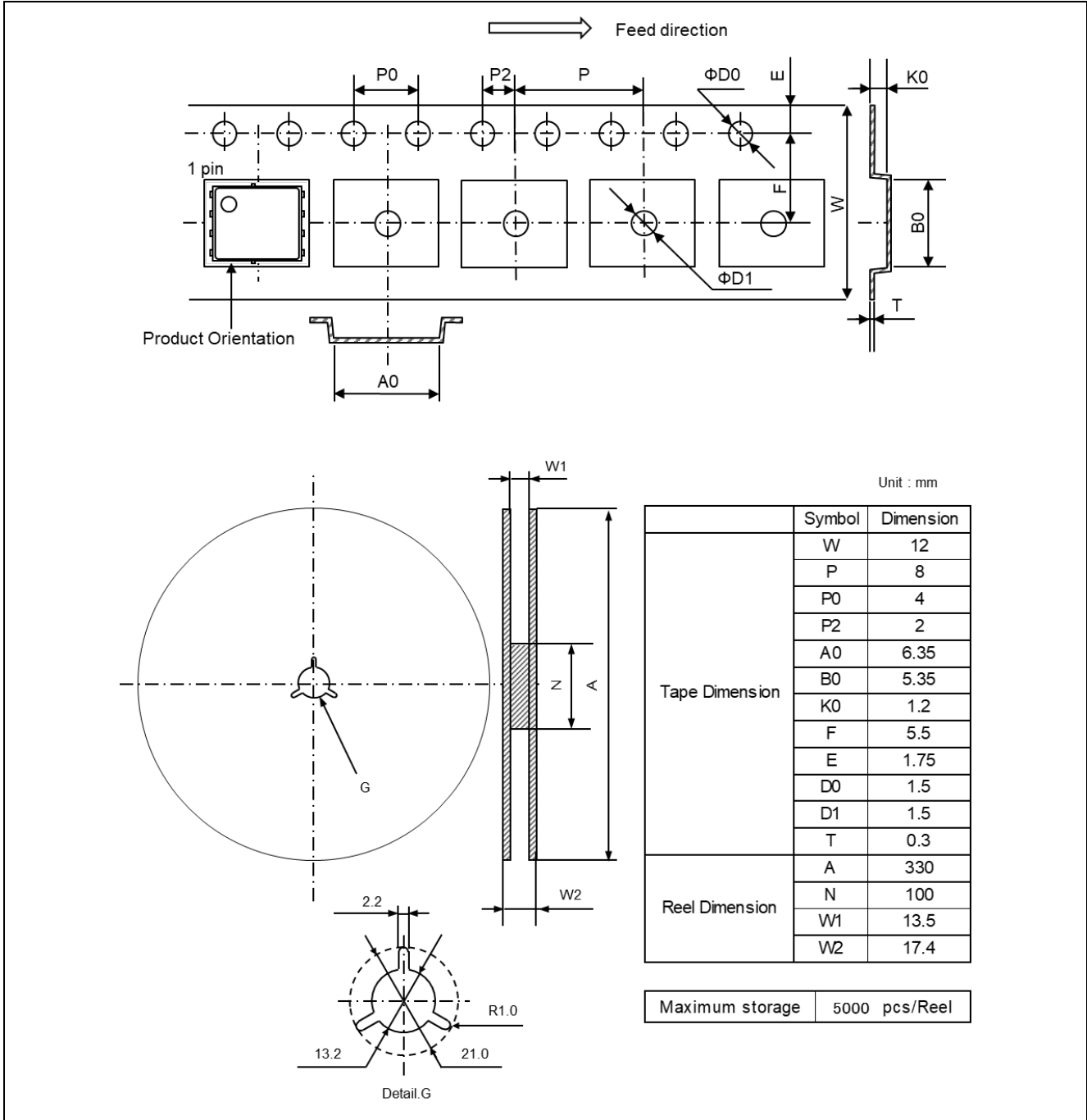
Mount pad



Ordering Information

Part No.	Packing	Quantity
RBE023N04R0SZN6#HB0	Taping	5000pcs/reel

Packing Specification



Remark : Strong electric field, when exposed to this device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it once, when it has occurred.

Continuous heavy condition (e.g. high temperature/voltage/current or high variation of temperature) may affect reliability even if it is within the absolute maximum ratings. Please consider derating condition for appropriate reliability in reference Renesas Semiconductor Reliability Handbook.

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